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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAF2015RJ

Silicon N Channel MOS FET Series **Power Switching**

REJ03G1141-0300 Rev.3.00 Aug 27, 2007

Description

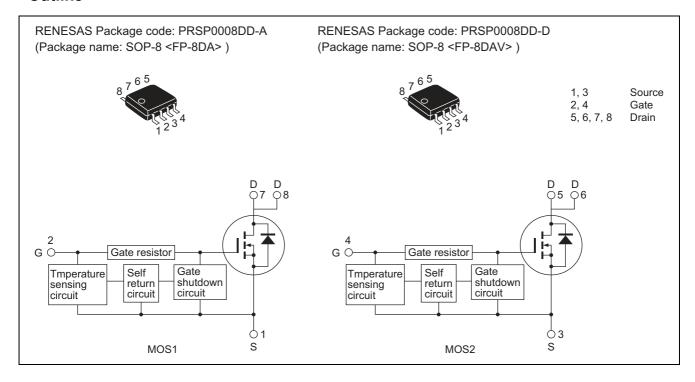
This FET has the over temperature shut-down capability sensing to the junction temperature.

This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

Features

- Logic level operation (5 to 6 V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Temperature hysteresis type.
- High density mounting.

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	16	V
	V _{GSS}	-2.5	V
Drain current	I _D	2	Α
Drain peak current	I _{D (pulse)} Note 1	4	Α
Body-drain diode reverse drain current	I _{DR}	2	Α
Avalanche current	I _{AP} Note 4	0.54	А
Avalanche energy	E _{AR} Note 4	25	mJ
Channel dissipation	Pch Note 2	2	W
Channel dissipation	Pch Note 3	1.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

- Notes: 1. $PW \le 10 \infty$, duty cycle $\le 1\%$
 - 2. 1 Drive operation: When using the glass epoxy board (FR4 40 \cdot 40 \cdot 1.6 mm), PW \leq 10 s
 - 3. 2 Drive operation: When using the glass epoxy board (FR4 40 \cdot 40 \cdot 1.6 mm), PW \leq 10 s
 - 4. Tch = 25°C, Rg > 50 Ω

Typical Operation Characteristics

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	_	_	V	
	V _{IL}	_	_	1.2	V	
Input current	I _{IH1}	_	_	100	∞A	$Vi = 5 V, V_{DS} = 0$
(Gate non shut down)	I _{IH2}	_	_	50	∞A	$Vi = 3.5 V, V_{DS} = 0$
	I _{IL}	_	_	1	∞A	$Vi = 1.2 V, V_{DS} = 0$
Input current	I _{IH (sd) 1}	_	0.53	_	mA	$Vi = 8 V, V_{DS} = 0$
(Gate shut down)	I _{IH (sd) 2}	_	0.2	_	mA	$Vi = 3.5 V, V_{DS} = 0$
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Hysteresis temperature	Thr	_	120	_	°C	Channel temperature
Gate operation voltage	V _{OP}	3.5	_	12	V	

Electrical Characteristics

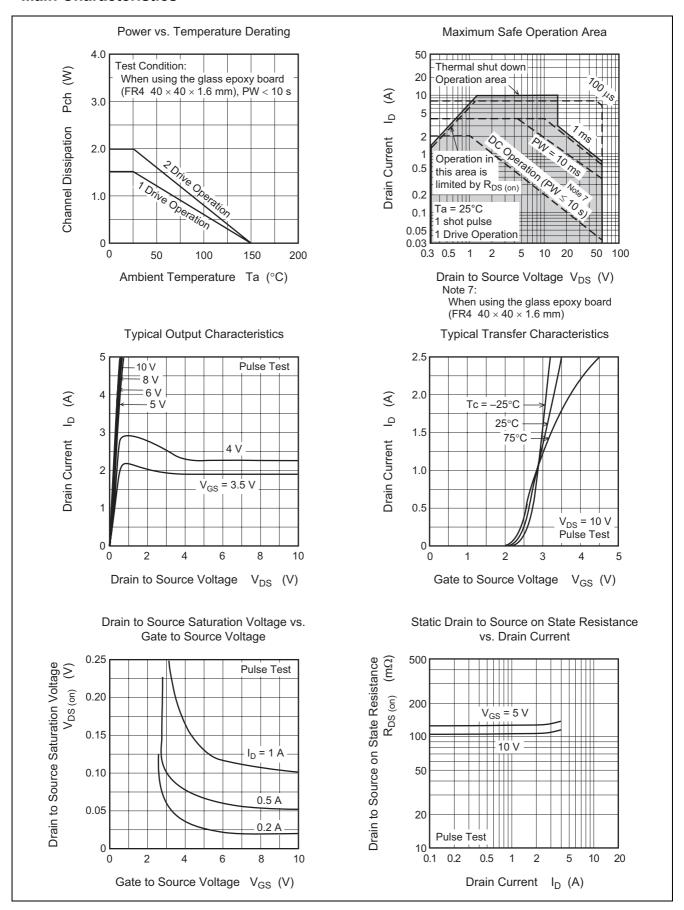
 $(Ta = 25^{\circ}C)$

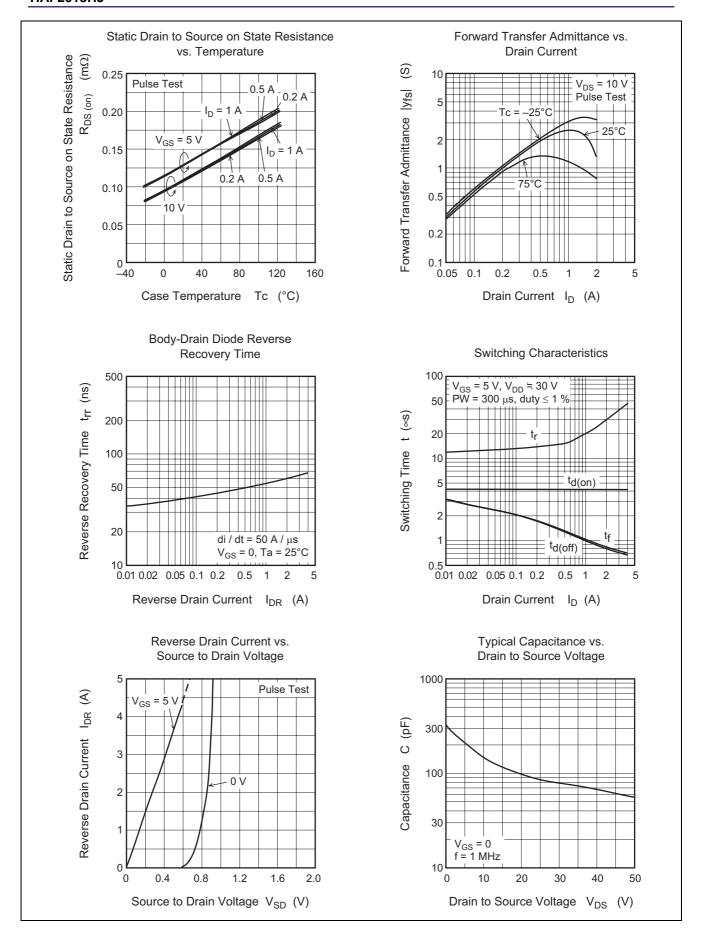
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	0.7	_	_	Α	$V_{GS} = 3.5 \text{ V}, V_{DS} = 2 \text{ V}$
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 2 V
Drain to source breakdown voltage	V _{(BR) DSS}	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V (BR) GSS	16	_	_	V	$I_{G} = 500 \propto A, V_{DS} = 0$
	V _(BR) GSS	-2.5	_	_	V	$I_G = -100 \propto A, V_{DS} = 0$
Gate to source leak current	I _{GSS1}	_	_	100	∞A	$V_{GS} = 5 \text{ V}, V_{DS} = 0$
	I _{GSS2}	_	_	50	∞A	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
	I _{GSS3}	_	_	1	∞A	$V_{GS} = 1.2 \text{ V}, V_{DS} = 0$
	I _{GSS4}	_	_	-100	∞A	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I _{GS (op) 1}		0.53		mA	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I _{GS (op) 2}		0.2		mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS1}			10	∞A	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
	I _{DSS2}			10	∞A	$V_{DS} = 48 \text{ V}, V_{GS} = 0$
						Ta = 125°C
Gate to source cutoff voltage	V _{GS (off)}	1.4	_	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	R _{DS (on)}	_	130	200	mΩ	$I_D = 1 A, V_{GS} = 5 V^{Note 5}$
	R _{DS (on)}	_	110	160	mΩ	$I_D = 1 A, V_{GS} = 10 V^{Note 5}$
Forward transfer admittance	y _{fs}	0.5	2.5		S	$I_D = 1 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 5}}$
Output capacitance	Coss		139		pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0$
						f = 1 MHz
Turn-on delay time	t _{d (on)}		4.2		≪s	I _D = 1 A
Rise time	t _r		20		≪s	$V_{GS} = 5 V$
Turn-off delay time	t _{d (off)}		1		≪S	$R_L = 30 \Omega$
Fall time	t _f		1		≪S	
Body-drain diode forward voltage	V_{DF}	_	0.82	_	V	$I_F = 2 A, V_{GS} = 0$
Body-drain diode reverse recovery time	t _{rr}	_	55	_	ns	$I_F = 2 A, V_{GS} = 0$
						di _F /dt = 50 A/∞s
Over load shut down operation time Note6	t _{os1}	_	15	_	ms	$V_{GS} = 5 \text{ V}, V_{DD} = 16 \text{ V}$

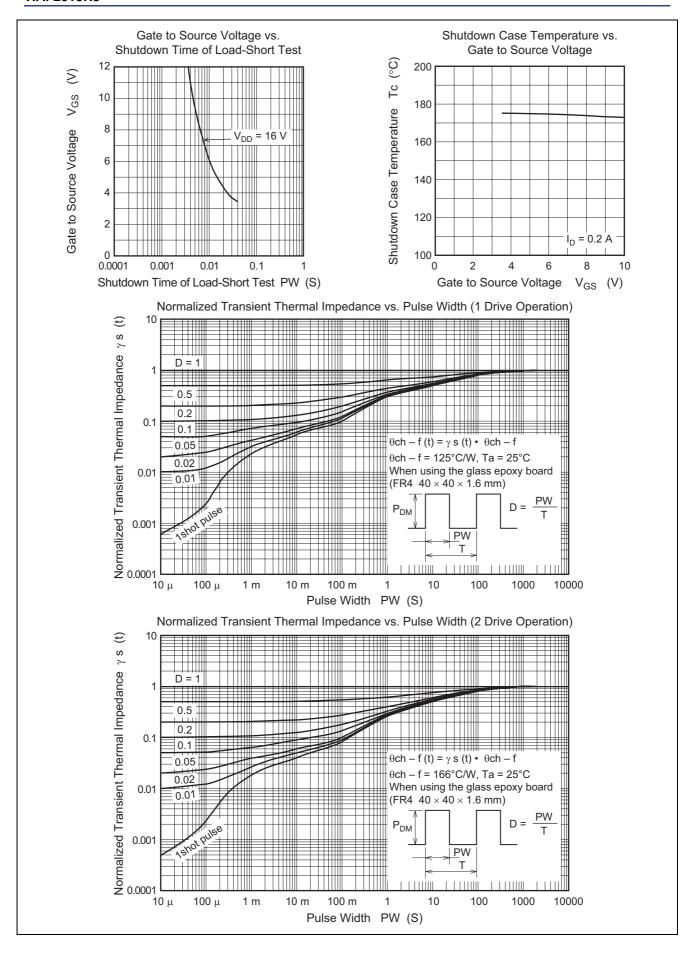
Notes: 5. Pulse test

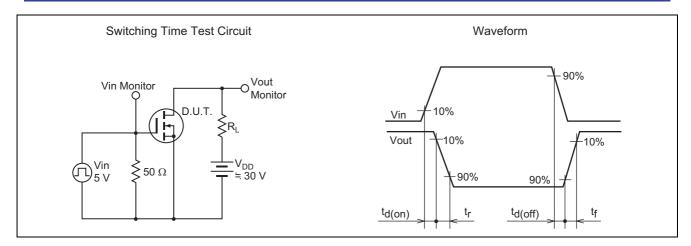
^{6.} Including the junction temperature rise of the over loaded condition.

Main Characteristics

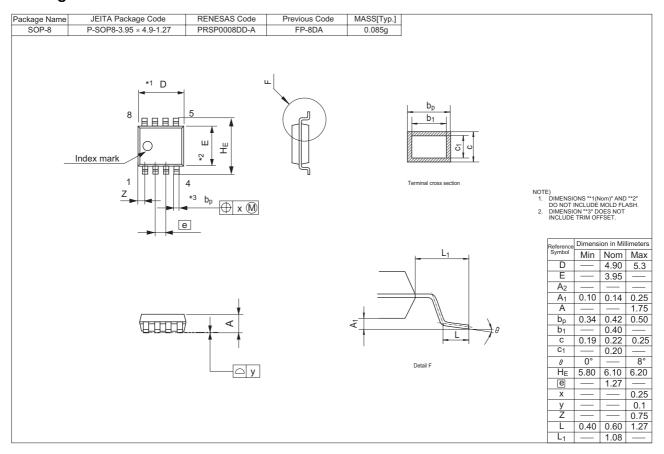


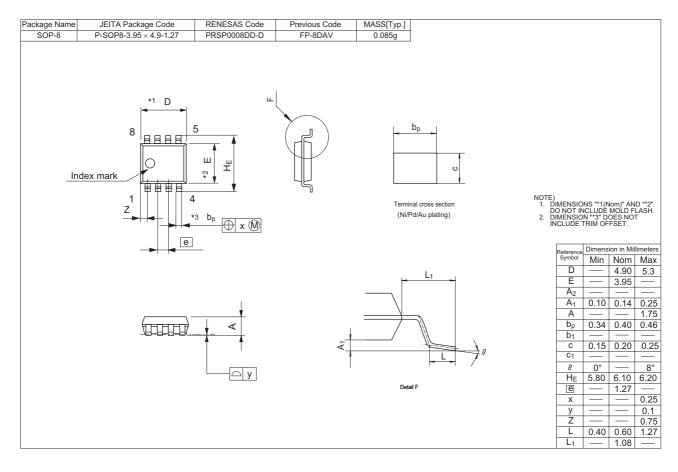






Package Dimensions





HAF2015RJ

Ordering Information

Part No.	Quantity	Shipping Container
HAF2015RJ-EL	2500 pcs/Reel	Embossed tape

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